



Thick Film Microcircuits - Design Guidelines

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|--|--|---|--|
| SUBSTRATES | Standard materials | Alumina 90%, 96% Aluminium nitride (AlN) | |
| | Other materials | Sapphire Machineable ceramic | |
| | Standard thicknesses | 0.254 - 1.00 mm (in 0.127 mm steps) 1.27 - 2.00 mm (in 0.254 mm steps) | |
| | Thickness tolerances | As fired | ± 10% (standard) ± 7% (premium) |
| | | Lapped | ± 0.02 mm |
| | Standard sizes | 25.4 x 25.4, 50.8 x 50.8, 57.15 x 57.15, 76.2 x 76.2, 114.3 x 114.3 mm | |
| | Surface finish - Alumina (96%) Alumina (90%) Surface finish - AlN | < 0.89 µm Ra < 1.14 µm Ra < 0.81 µm Ra | |
| Camber | Standard Premium | ± 0.076 mm/mm ± 0.051 mm /mm | |
| IMAGING | Maximum printed area (typical) Printed area maximum (absolute) | 76.2 x 76.2 mm 101.6 x 101.6 mm | |
| | Typical pattern position tolerance | Printed ± 0.05 mm | Photo-imaged ± 0.02 mm |
| CONDUCTORS | Minimum line width/space Typical line width/space Minimum line width tolerance Typical line width tolerance | Printed 50 µm 150 µm ± 25 µm ± 50 µm | Photo-imaged 25 µm 50 µm ± 10 µm ± 20 µm |
| | Print thickness (typical) Fine Au Normal maximum range | 8 - 12 µm 5 - 8 µm 4 - 18 µm | |
| | Minimum metallisation around vias | Via dia. + 100 µm | |
| | METALLISED THRU HOLES / FILLED VIAS | Minimum aspect ratio Maximum substrate thickness (typical) | 0.3:1 Hole diameter:substrate thickness 1.00 mm (deeper design dependent) |
| Typical hole diameter Minimum hole diameter | | Substrate thickness 75% of substrate thickness | |
| Minimum hole to hole web thickness or hole to edge web distance | | Substrate thickness | |
| RESISTORS | Printed resistor values (typical) Resistor tolerance | 10 - 100 ohms/sq (blended/trimmed) ± 0.30 ohms achievable | |
| | Minimum resistor dimension(s) Minimum probe point dimensions | 0.250 mm 0.125 x 0.125 mm (> 0.25 mm preferable) | |
| | Maximum probe to resistor dimension Maximum substrate size | 20.00 mm 114.30 x 114.30 mm | |

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| LASER PROFILING | Maximum substrate size | 150 x 150 mm | |
| | Maximum substrate thickness | 1.0 mm | |
| | Lasered feature tolerance | ± 30 µm | |
| | Lasered feature position tolerance | ± 30 µm | |
| | Minimum lasered feature to pattern gap | 30 µm | |
| | Lasered feature to pattern tolerance | ± 30 µm | |
| | Typical laser taper | ± 50 µm / mm | |
| | Minimum distance hole to hole, hole to edge | = Substrate thickness | |
| DIAMOND SAWING | Maximum substrate thickness for dicing | 2.0 mm | |
| | Maximum substrate size | Rectangular: | 127 x 127 mm |
| | | Circular: | 150 mm dia. |
| | Minimum distance pattern to edge | 0.030 mm | |
| | Typical distance pattern to edge | 0.050 mm | |
| | Minimum dicing tolerance | ± 0.025 mm | |
| | Typical dicing tolerance | ± 0.050 mm | |
| | Typical blade width | Substrate Thickness | Blade Width |
| | | < 0.5 mm | 0.2 mm |
| | | 0.5-1.0 mm | 0.3 mm |
| | | > 1.0 mm | 0.4 mm |
| METALLISATIONS | Conductor layers | Au, Pt/Au, Pt/Ag/Pd, Ag/Pd, Mo/Mn | |
| | Solder dams, layer barriers | Dielectric | |
| | Pre-deposited solder | Au/Sn, Sn/Ag | |
| OTHER | Wrap over edges (single and multi), multi layers, double sided circuits, thru hole printing, passive component mounting, wire bonding, angled face printing/wrap over, mixed metal circuits, pre-deposited solder. | | |
| GENERAL | Actual capabilities are application specific and will depend on the interactions between the substrate material, metallisation scheme, vias, apertures, line widths, line spacing, conductor thickness, resistor geometry, etc. Generally the more complicated the circuit and the tighter the tolerances the lower the yield and thus the higher the cost. Selection of metallisation schemes is dependant on requirements for solderability, wire bondability and temperature resistance as well as electrical and dimensional performance. | | |
| DATA FORMAT | DWG, DXF, Gerber, GDSII | AutoCAD preferred | |
| <p>LEW Techniques specialises in the manufacture of miniature components and microcircuits for mounting of semiconductor devices. Our in-house capabilities include thin film, thick film and refractory metallising of ceramics and metals, electroplating, laser machining and marking, precision dicing, atmosphere/vacuum brazing and solder assembly.</p> <p>To discuss your application in detail please contact our Technical Sales Department who will be pleased to assist you.</p> | | | |

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Rev2 – Oct 2010